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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant

: Lars-Peter Heimeck et al.

Applic. No.

: 09/885,553

Filed

: June 20, 2001

Title

Ands N/E Imavillar 2/06/03 Memory : MOS Transistor in a Single-Transistor Memor

Cell Having a Locally Thickened Gate Oxide

Examiner

: Johannes P. Mondt

Group Art Unit: 2826

TC 2800 MAIL ROO

## AMENDMENT under 37 C.F.R. § 1.116

## BOX AF

Hon. Commissioner of Patents and Trademarks, Washington, D. C. 20231

## Sir:

Responsive to the final Office action dated November 13, 2002 kindly amend the above-identified application as follows:

## In the Claims:

Claim 1 (Twice amended). A MOS transistor in a singletransistor memory cell, comprising: